

2SA2092

Transistors

-1A / -60V Bipolar transistor

2SA2092

●Applications

High-speed switching, low frequency amplification

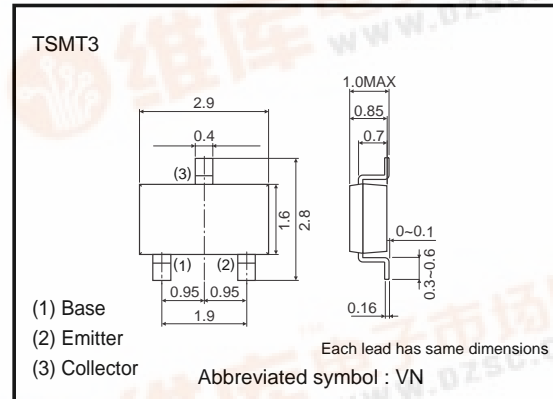
●Feature

- 1) High speed switching. (tf : Typ. : 30ns at Ic = -1A)
- 2) Low saturation voltage.
(Typ. : -200mV at Ic = -500mA, Ib = -50mA)
- 3) Strong discharge resistance for inductive load and capacitance load.
- 4) Low switching noise.

●Structure

PNP epitaxial planar silicon transistor

●External dimensions (Unit : mm)



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Collector-base voltage	V _{CB0}	-60	V	
Collector-emitter voltage	V _{CE0}	-60	V	
Emitter-base voltage	V _{EB0}	-6	V	
Collector current	DC	I _c	-1	A
	PULSE	I _{CP} *1	-2	A
Power dissipation	P _c *2	500	mW	
Junction temperature	T _j	150	°C	
Range of storage temperature	T _{stg}	-55 to +150	°C	

*1 Pw=10ms

*2 Each terminal mounted on a recommended land

●Packaging specifications

Package	TSMT3
Package type	Taping
Code	TL
Part No.	Basic ordering unit (pieces)
2SA2092	3000

●hFE rank

Q
120-270

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV _{CEO}	-60	-	-	V	I _c = -1mA
Collector-base breakdown voltage	BV _{CBO}	-60	-	-	V	I _c = -100μA
Emitter-base breakdown voltage	BV _{EB0}	-6	-	-	V	I _E = -100μA
Collector cut-off current	I _{CBO}	-	-	-1.0	μA	V _{CB} = -40V
Emitter cut-off current	I _{EB0}	-	-	-1.0	μA	V _{EB} = -4V
Collector-emitter saturation voltage	V _{CE(sat)}	-	-200	-500	mV	I _c = -500mA, I _B = -50mA
DC current gain	h _{FE} *3	120	-	270	-	V _{CE} = -2V, I _c = -100mA
Transition frequency	f _t *1	-	300	-	MHz	V _{CE} = -10V, I _E = 100mA, f = 10MHz
Collector output capacitance	C _{ob}	-	15	-	pF	V _{CB} = -10V, I _E = 0, f = 1MHz
Turn-on time	t _{on}	-	30	-	ns	I _c = -1A, I _{B1} = -100mA
Storage time	t _{stg}	-	100	-	ns	I _{B2} = 100mA
Fall time	t _f *2	-	30	-	ns	V _{CC} = -25V

*1 Pulse measurement

*2 See switching test circuit

*3 hFE rank

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● Electrical characteristics curve

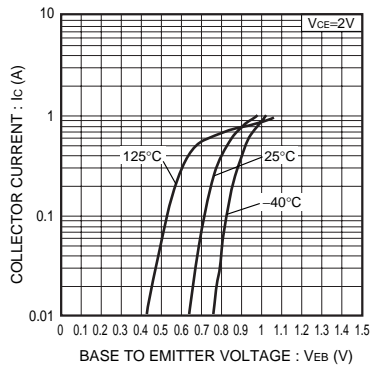


Fig.1 Grounded emitter propagation characteristics

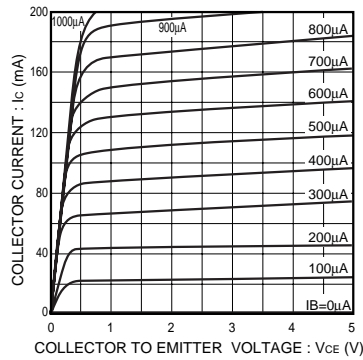


Fig.2 Typical output characteristics

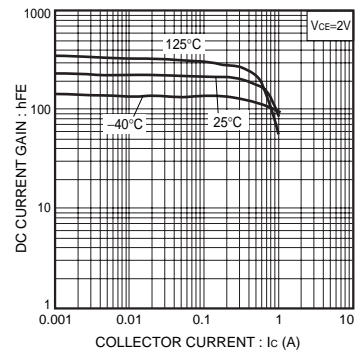


Fig.3 DC current gain vs. collector current (I)

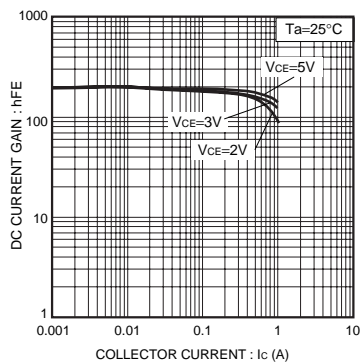


Fig.4 DC current gain vs. collector current (II)

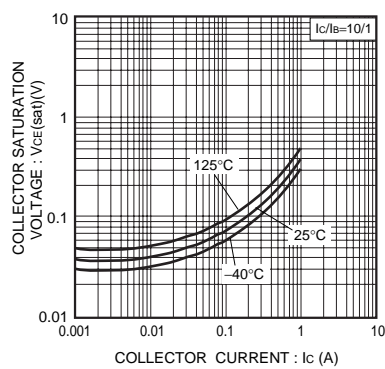


Fig.5 Collector-emitter saturation voltage vs. collector current (I)

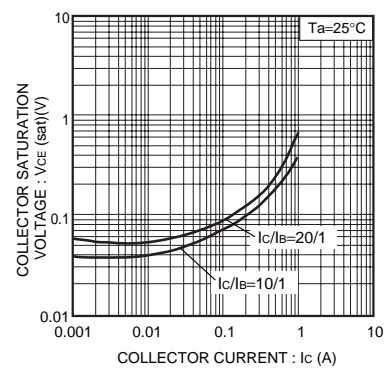


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

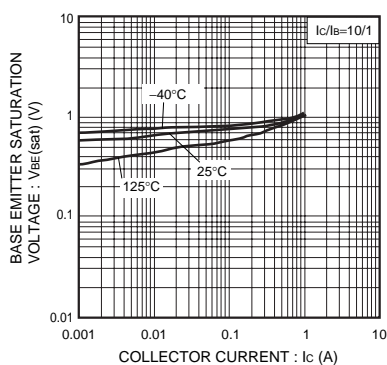


Fig.7 Base-emitter saturation voltage vs. collector current

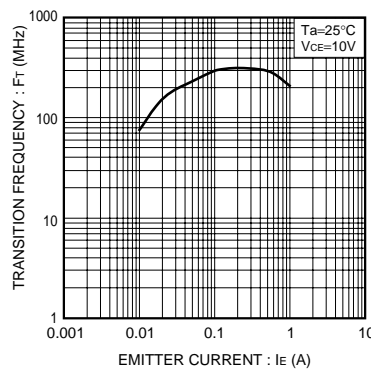


Fig.8 Transition frequency

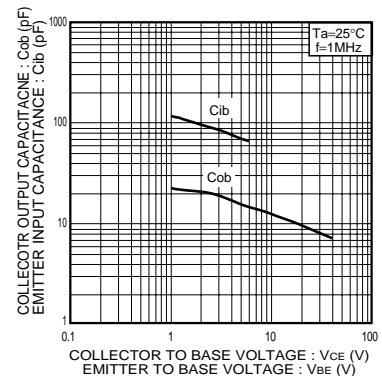


Fig.9 Collector output capacitance
Emitter input capacitance

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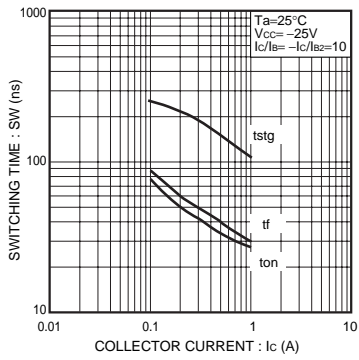


Fig.10 Switching Time

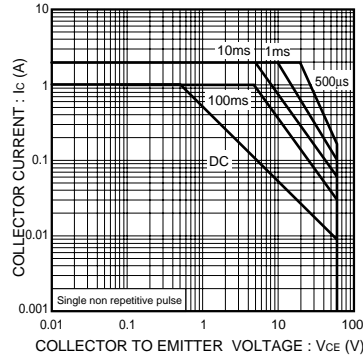
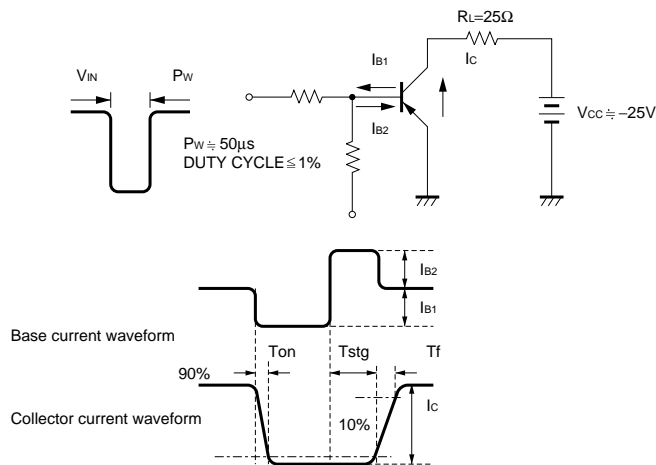


Fig.11 Safe operating area

●Switching test circuit



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